LM119QML High Speed Dual Comparator

Check for Samples: LM119QML

FEATURES

- **Available with radiation ensured**
  - **High Dose Rate 100 krad(Si)**
  - **ELDRS Free 100 krad(Si)**
- **Two independent comparators**
- **Operates from a single 5V supply**
- **Typically 80 ns response time at ±15V**
- **Minimum fan-out of 2 each side**
- **Maximum input current of 1 µA over temperature**
- **Inputs and outputs can be isolated from system ground**
- **High common mode slew rate**

DESCRIPTION

The LM119 is a precision high speed dual comparator fabricated on a single monolithic chip. It is designed to operate over a wide range of supply voltages down to a single 5V logic supply and ground. Further, it has higher gain and lower input currents than devices like the LM710. The uncommitted collector of the output stage makes the LM119 compatible with RTL, DTL and TTL as well as capable of driving lamps and relays at currents up to 25 mA.

Although designed primarily for applications requiring operation from digital logic supplies, the LM119 is fully specified for power supplies up to ±15V. It features faster response than the LM111 at the expense of higher power dissipation. However, the high speed, wide operating voltage range and low package count make the LM119 much more versatile than older devices like the LM711.

Connection Diagrams

CDIP Package

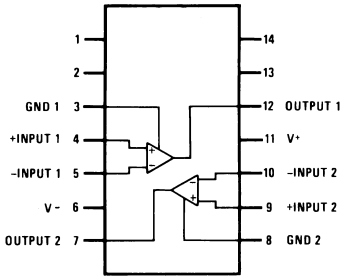


Figure 1. Top View
Package Number J0014A

LCCC Package

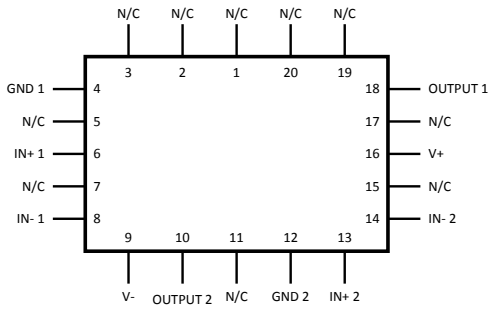
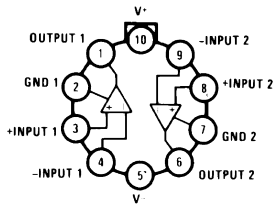


Figure 2. Top View
Package Number NAJ0020A

TO-100 Package



Case is connected to pin 5 (V^-).

Figure 3. Top View
Package Number LME0010C

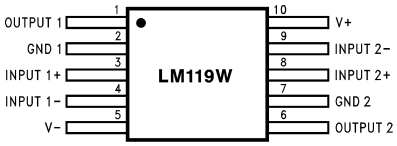


Figure 4. Top View
Package Number NAD0010A, NAC0010A

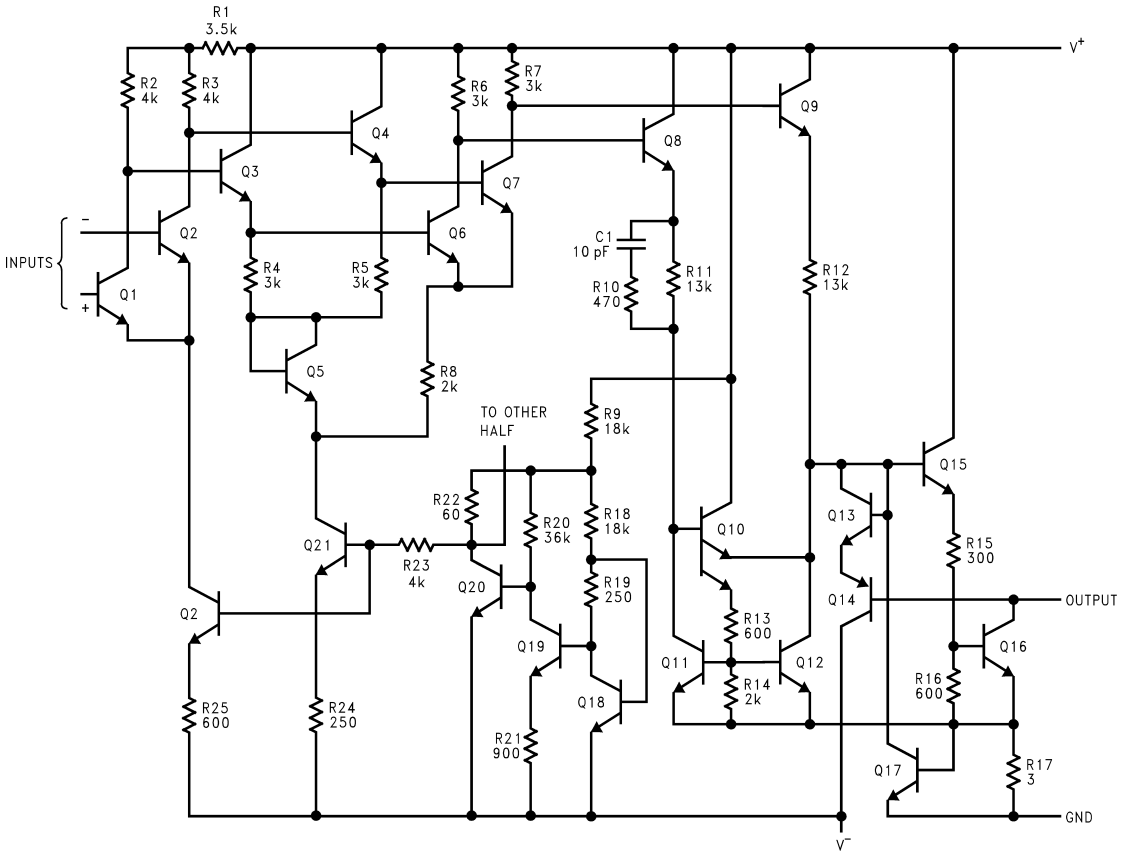
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Schematic Diagram



*Do not operate the LM119 with more than 16V between GND and V^+

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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Absolute Maximum Ratings (1)

Total Supply Voltage	36V
Output to Negative Supply Voltage	36V
Ground to Negative Supply Voltage	25V
Ground to Positive Supply Voltage	18V
Differential Input Voltage	±5V
Input Voltage (2)	±15V
Power Dissipation (3)	500 mW
Output Short Circuit Duration	10 sec
Storage Temperature Range	$-65°C \le T_A \le 150°C$
Operating Ambient Temperature Range	$-55°C \le T_A \le 125°C$
Maximum Junction Temperature (T_J)	150°C
Lead Temperature (Soldering, 10 sec.)	260°C
Thermal Resistance	
θ_{JA}	
LCCC Package (Still Air)	89°C/W
LCCC Package (500LF/Min Air flow)	63°C/W
TO-100 Package (Still Air)	162°C/W
TO-100 Package (500LF/Min Air flow)	88°C/W
CDIP Package (Still Air)	94°C/W
CDIP Package (500LF/Min Air flow)	52°C/W
CLGA Package (Still Air)	215°C/W
CLGA Package (500LF/Min Air flow)	132°C/W
CLGA Package (Still Air)	215°C/W
CLGA Package (500LF/Min Air flow)	132°C/W
θ_{JC}	
LCCC Package	5°C/W
TO-100 Package	31°C/W
CDIP Package	11°C/W
CLGA Package	13°C/W
CLGA Package	13°C/W
Package Weight	
LCCC Package	TBD
TO-100 Package	TBD
CDIP Package	TBD
CLGA Package	TBD
CLGA Package	225mg
ESD rating (4)	800V

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

(2) For supply voltages less than ±15V the absolute maximum input voltage is equal to the supply voltage.

(3) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is $P_{Dmax} = (T_{Jmax} - T_A)/\theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower.

(4) Human Body model, 1.5KΩ in series with 100pF.

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Table 1. Quality Conformance Inspection(1)

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

(1) Mil-Std-883, Method 5005 - Group 5

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LM119/883 Electrical Characteristics DC Parameters

The following conditions apply, unless otherwise specified. V_{CM} = 0V

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$+I_{CC}$	Positive Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ			11	mA	1
					11.5	mA	2
$-I_{CC}$	Negative Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ		-4.2		mA	1
				-4.5		mA	2
I_{Leak}	Output Leakage Current	$^+V_{CC}$ = 15V, $^-V_{CC}$ = -1V, V_{Gnd} = 0V, V_O = 35V, V_I = 5mV			1.8	µA	1
					9.5	µA	2
					10.0	µA	3
I_{IB}	Input Bias Current	$\pm V_{CC}$ = ±15V			0.475	µA	1
					0.95	µA	2, 3
		$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, V_{CM} = 1.5V			0.475	µA	1
					.95	µA	2, 3
V_{IO}	Input Offset Voltage	$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, V_{CM} = 1V, R_S ≤ 5KΩ		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
		$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, V_{CM} = 3V, R_S ≤ 5KΩ		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V, R_S ≤ 5KΩ		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = -12V, R_S ≤ 5KΩ		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
I_{IO}	Input Offset Current	$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, V_{CM} = 1V		-75	75	nA	1
				-100	100	nA	2, 3
		$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, V_{CM} = 3V		-75	75	nA	1
				-100	100	nA	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V		-75	75	nA	1
				-100	100	nA	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = -12V		-75	75	nA	1
				-100	100	nA	2, 3
V_{Sat}	Output Saturation Voltage	$\pm V_{CC}$ = ±15V, I_O = 25mA, V_I = -5mV			1.5	V	1
		$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, I_O= 4.0mA	(1)		0.4	V	1, 2
			(1)		0.6	V	3
A_V	Voltage Gain	$\pm V_{CC}$ = ±15V, Delta V_O = 12V, R_L = 1.4KΩ	(2), (3)	10.5		K	4
			(2), (3)	10		K	5, 6
		$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, Delta V_O = 4.5V, R_L = 1.4KΩ	(2), (4)	8.0		K	4
			(2), (4)	5.0		K	5
			(2), (4)	5.8		K	6

(1) Output is monitored by measuring V_I with limits from 0 to 6mV at all temperatures
(2) K = V/mV.
(3) Gain is computed with an output swing from +13.5V to +1.5V.
(4) Gain is computed with an output swing from +5.0V to +0.5V.

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LM119-SMD Electrical Characteristics SMD 8601401 DC Parameters

The following conditions apply, unless otherwise specified. V_{CM} = 0V

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$+I_{CC}$	Positive Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ			11	mA	1
					11.5	mA	2, 3
$-I_{CC}$	Negative Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ		-4.2		mA	1
				-4.5		mA	2
				-6.0		mA	3
I_{Leak}	Output Leakage Current	$^+V_{CC}$ = 15V, $^-V_{CC}$ = -1V, V_{Gnd} = 0V, V_O = 35V	(1)		1.8	µA	1
			(1)		10	µA	2, 3
I_{IB}	Input Bias Current	$\pm V_{CC}$ = ±15V			0.475	µA	1
					0.95	µA	2, 3
		$^+V_{CC}$ = 5V	(2)		0.475	µA	1
			(2)		.95	µA	2, 3
V_{IO}	Input Offset Voltage	$^+V_{CC}$ = 5V, V_{CM} = 1V, R_S ≤ 5KΩ	(2)	-3.8	3.8	mV	1
			(2)	-6.8	6.8	mV	2, 3
		$^+V_{CC}$ = 5V, V_{CM} = 3V, R_S ≤ 5KΩ	(2)	-3.8	3.8	mV	1
			(2)	-6.8	6.8	mV	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V, R_S ≤ 5KΩ		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = -12V, R_S ≤ 5KΩ		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
I_{IO}	Input Offset Current	$^+V_{CC}$ = 5V, V_{CM} = 1V	(2)	-75	75	nA	1
			(2)	-100	100	nA	2, 3
		$^+V_{CC}$ = 5V, V_{CM} = 3V	(2)	-75	75	nA	1
			(2)	-100	100	nA	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V		-75	75	nA	1
				-100	100	nA	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = -12V		-75	75	nA	1
				-100	100	nA	2, 3
V_I	Input Voltage Range	$^+V_{CC}$ = 5V	(2), (3)	1.0	3.0	V	1, 2, 3
		$\pm V_{CC}$ = ±15V	(3)	-12	12	V	1, 2, 3
V_{Sat}	Output Saturation Voltage	$\pm V_{CC}$ = ±15V, I_O = 25mA, V_I ≤ -5mV	(1)		1.5	V	1, 2, 3
		$^+V_{CC}$ = 3.5V, $^-V_{CC}$ = -1V, V_I ≤ -6mV, I_O ≤ 3.2mA			0.4	V	1, 2
					0.6	V	3
A_V	Voltage Gain	$\pm V_{CC}$ = ±15V, Delta V_O = 12V, R_L = 1.4KΩ	(4)	10.5		K	4
			(4)	10		K	5, 6
		$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, Delta V_O = 4.5V, R_L = 1.4KΩ	(2), (4)	8.0		K	4
			(2), (4)	5.0		K	5
			(2), (4)	5.8		K	6
CMRR	Common Mode Rejection Ratio	$\pm V_{CC}$ = ±15V, V_{CM} = ±12V		80		dB	4

(1) V_I ≥ 8mV at extremes for I_{Leak} and V_I ≤ −8mV at extremes for V_{Sat} (V_I to exceed V_{OS}.
(2) 5V differential across $+V_{CC}$ and $-V_{CC}$.
(3) Parameter ensured by V_{IO} and I_{IO} tests.
(4) K = V/mV.

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LM119 Electrical Characteristics SMD 5962-9679801, HIGH DOSE RATE DC Parameters

The following conditions apply, unless otherwise specified. V_{CM} = 0V

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$+I_{CC}$	Positive Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ			11	mA	1
					11.5	mA	2, 3
$-I_{CC}$	Negative Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ		-4.2		mA	1
				-4.5		mA	2
				-6.0		mA	3
I_{Leak}	Output Leakage Current	$^+V_{CC}$ = 15V, $^-V_{CC}$ = -1V, V_{Gnd} = 0V, V_O = 35V	(1)		1.8	µA	1
			(1)		10	µA	2, 3
I_{IB}	Input Bias Current	$\pm V_{CC}$ = ±15V			0.475	µA	1
					0.95	µA	2, 3
		$^+V_{CC}$ = 5V	(2)		0.475	µA	1
			(2)		.95	µA	2, 3
V_{IO}	Input Offset Voltage	$^+V_{CC}$ = 5V, V_{CM} = 1V, $R_S \le 5K\Omega$	(2)	-3.8	3.8	mV	1
			(2)	-6.8	6.8	mV	2, 3
		$^+V_{CC}$ = 5V, V_{CM} = 3V, $R_S \le 5K\Omega$	(2)	-3.8	3.8	mV	1
			(2)	-6.8	6.8	mV	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V, $R_S \le 5K\Omega$		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = -12V, $R_S \le 5K\Omega$		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
I_{IO}	Input Offset Current	$^+V_{CC}$ = 5V, V_{CM} = 1V	(2)	-75	75	nA	1
			(2)	-100	100	nA	2, 3
		$^+V_{CC}$ = 5V, V_{CM} = 3V	(2)	-75	75	nA	1
			(2)	-100	100	nA	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V		-75	75	nA	1
				-100	100	nA	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = -12V		-75	75	nA	1
				-100	100	nA	2, 3
V_I	Input Voltage Range	$^+V_{CC}$ = 5V	(2), (3)	1.0	3.0	V	1, 2, 3
		$\pm V_{CC}$ = ±15V	(3)	-12	12	V	1, 2, 3
V_{Sat}	Output Saturation Voltage	$\pm V_{CC}$ = ±15V, I_O = 25mA, $V_I \le$ -5mV	(1)		1.5	V	1, 2, 3
		$^+V_{CC}$ = 3.5V, $^-V_{CC}$ = -1V, $V_I \le$ -6mV, $I_O \le$ 3.2mA			0.4	V	1, 2
					0.6	V	3
A_V	Voltage Gain	$\pm V_{CC}$ = ±15V, Delta V_O = 12V, R_L = 1.4KΩ	(4)	10.5		K	4
			(4)	10		K	5, 6
		$^+V_{CC}$ = 5V, $^-V_{CC}$ = 0V, Delta V_O = 4.5V, R_L = 1.4KΩ	(2), (4)	8.0		K	4
			(2), (4)	5.0		K	5
			(2), (4)	5.8		K	6
CMRR	Common Mode Rejection Ratio	$\pm V_{CC}$ = ±15V, V_{CM} = ±12V		80		dB	4

(1) $V_I \ge$ 8mV at extremes for I_{Leak} and $V_I \le$ −8mV at extremes for V_{Sat} (V_I to exceed V_{OS}.
(2) 5V differential across $+V_{CC}$ and $-V_{CC}$.
(3) Parameter ensured by V_{IO} and I_{IO} tests.
(4) K = V/mV.

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SMD 5962-9679801, HIGH DOSE RATE DC DELTA Parameters

The following conditions apply, unless otherwise specified.

V_{CM} = 0V, Delta calculations performed on QMLV devices at group B, subgroup 5 only.

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$+I_{CC}$	Positive Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ		-1.0	1.0	mA	1
$-I_{CC}$	Negative Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ		-0.5	0.5	mA	1
V_{IO}	Input Offset Voltage	$^+V_{CC}$ = 5V, V_{CM} = 1V, $R_S \leq$ 5KΩ		-0.4	0.4	mV	1

SMD 5962-9679801, High Dose Rate 100K Post Radiation Parameters @ 25°C (1)

The following conditions apply, unless otherwise specified. V_{CM} = 0V

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
I_{IB}	Input Bias Current	$\pm V_{CC}$ = ±15V			1.0	µA	1
		V_{CC} = 5V			1.0	µA	1
V_{IO}	Input Offset Voltage	$^+V_{CC}$ = 5V, V_{CM} = 1V, $R_S \leq$ 5KΩ		-4.0	4.0	mV	1
		$^+V_{CC}$ = 5V, V_{CM} = 3V, $R_S \leq$ 5KΩ		-4.0	4.0	mV	1
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V, $R_S \leq$ 5KΩ		-4.0	4.0	mV	1
		$\pm V_{CC}$ = ±15V, V_{CM} = −12V, $R_S \leq$ 5KΩ		-4.0	4.0	mV	1

(1) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate sensitivity. Radiation end point limits for the noted parameters are ensured only for the conditions as specified in MIL-STD-883, per Test Method 1019, Condition A.

LM119 Electrical Characteristics SMD 5962-9679802, ELDRS FREE DC Parameters

The following conditions apply, unless otherwise specified. V_{CM} = 0V

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$+I_{CC}$	Positive Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ			11	mA	1
					11.5	mA	2, 3
$-I_{CC}$	Negative Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ		-4.2		mA	1
				-4.5		mA	2
				-6.0		mA	3
I_{Leak}	Output Leakage Current	$^+V_{CC}$ = 15V, $^-V_{CC}$ = -1V, V_{Gnd} = 0V, V_O = 35V	(1)		1.8	µA	1
			(1)		10	µA	2, 3
I_{IB}	Input Bias Current	$\pm V_{CC}$ = ±15V			0.475	µA	1
					0.95	µA	2, 3
		$^+V_{CC}$ = 5V	(2)		0.475	µA	1
			(2)		.95	µA	2, 3

(1) $V_I \geq$ 8mV at extremes for I_{Leak} and $V_I \leq$ −8mV at extremes for V_{Sat} (V_I to exceed V_{OS}.

(2) 5V differential across $+V_{CC}$ and $-V_{CC}$.

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LM119 Electrical Characteristics SMD 5962-9679802, ELDRS FREE DC Parameters (continued)

The following conditions apply, unless otherwise specified. V_{CM} = 0V

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
V_{IO}	Input Offset Voltage	$^{+}V_{CC}$ = 5V, V_{CM} = 1V, $R_S \le 5K\Omega$	(2)	-3.8	3.8	mV	1
			(2)	-6.8	6.8	mV	2, 3
		$^{+}V_{CC}$ = 5V, V_{CM} = 3V, $R_S \le 5K\Omega$	(2)	-3.8	3.8	mV	1
			(2)	-6.8	6.8	mV	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V, $R_S \le 5K\Omega$		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = -12V, $R_S \le 5K\Omega$		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
I_{IO}	Input Offset Current	$^{+}V_{CC}$ = 5V, V_{CM} = 1V	(2)	-75	75	nA	1
			(2)	-100	100	nA	2, 3
		$^{+}V_{CC}$ = 5V, V_{CM} = 3V	(2)	-75	75	nA	1
			(2)	-100	100	nA	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V		-75	75	nA	1
				-100	100	nA	2, 3
		$\pm V_{CC}$ = ±15V, V_{CM} = -12V		-75	75	nA	1
				-100	100	nA	2, 3
V_I	Input Voltage Range	$^{+}V_{CC}$ = 5V	(3), (3)	1.0	3.0	V	1, 2, 3
		$\pm V_{CC}$ = ±15V	(3)	-12	12	V	1, 2, 3
V_{Sat}	Output Saturation Voltage	$\pm V_{CC}$ = ±15V, I_O = 25mA, $V_I \le$ -5mV	(1)		1.5	V	1, 2, 3
		$^{+}V_{CC}$ = 3.5V, $^{-}V_{CC}$ = -1V, $V_I \le$ -6mV, $I_O \le$ 3.2mA			0.4	V	1, 2
					0.6	V	3
A_V	Voltage Gain	$\pm V_{CC}$ = ±15V, Delta V_O = 12V, R_L = 1.4KΩ	(4)	10.5		K	4
			(4)	10		K	5, 6
		$^{+}V_{CC}$ = 5V, $^{-}V_{CC}$ = 0V, Delta V_O = 4.5V, R_L = 1.4KΩ	(5), (4)	8.0		K	4
			(5), (4)	5.0		K	5
			(5), (4)	5.8		K	6
CMRR	Common Mode Rejection Ratio	$\pm V_{CC}$ = ±15V, V_{CM} = ±12V		80		dB	4

(3) Parameter ensured by V_{IO} and I_{IO} tests.
(4) K = V/mV.
(5) 5V differential across $+V_{CC}$ and $-V_{CC}$.

SMD 5962-9679802, ELDRS FREE DC DELTA Parameters

The following conditions apply, unless otherwise specified.
V_{CM} = 0V, Delta calculations performed on QMLV devices at group B, subgroup 5 only.

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$+I_{CC}$	Positive Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ		-1.0	1.0	mA	1
$-I_{CC}$	Negative Supply Current	$\pm V_{CC}$ = ±15V, V_O = Low V^+ = 5.6V thru 1.4KΩ		-0.5	0.5	mA	1
V_{IO}	Input Offset Voltage	$^{+}V_{CC}$ = 5V, V_{CM} = 1V, $R_S \le 5K\Omega$		-0.4	0.4	mV	1

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SMD 5962-9679802, ELDRS FREE 100K Post Radiation Parameters @ 25°C (1)

The following conditions apply, unless otherwise specified. V_{CM} = 0V

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
I_{IB}	Input Bias Current	$\pm V_{CC}$ = ±15V			1.0	µA	1
		V_{CC} = 5V			1.0	µA	1
V_{IO}	Input Offset Voltage	$^{+}V_{CC}$ = 5V, V_{CM} = 1V, $R_S \leq 5K\Omega$		-4.0	4.0	mV	1
		$^{+}V_{CC}$ = 5V, V_{CM} = 3V, $R_S \leq 5K\Omega$		-4.0	4.0	mV	1
		$\pm V_{CC}$ = ±15V, V_{CM} = 12V, $R_S \leq 5K\Omega$		-4.0	4.0	mV	1
		$\pm V_{CC}$ = ±15V, V_{CM} = −12V, $R_S \leq 5K\Omega$		-4.0	4.0	mV	1

(1) Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. Low dose rate testing has been performed on a wafer-by-wafer basis, per Test Method 1019, Condition D of MIL-STD-883, with no enhanced low dose rate sensitivity (ELDRS).

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Typical Performance Characteristics

Input Currents

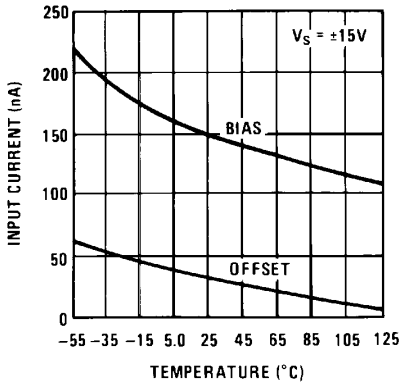


Figure 5.

Common Mode Limits

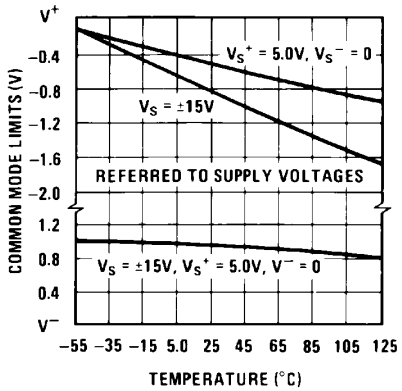


Figure 6.

Transfer Function

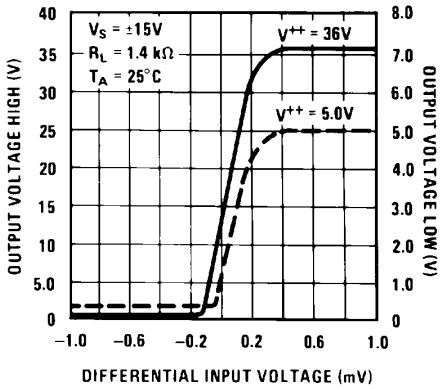


Figure 7.

Response Time for Various Input Overdrives

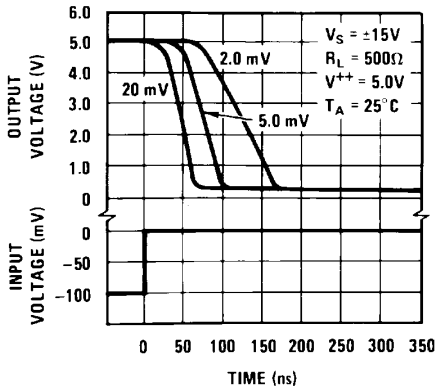


Figure 8.

Response Time for Various Input Overdrives

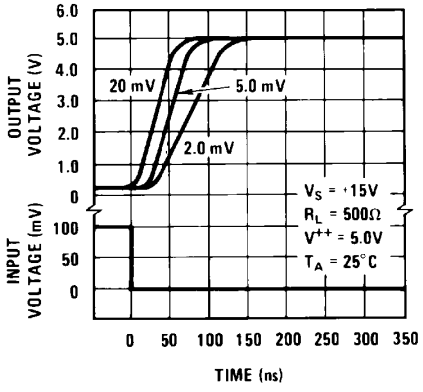


Figure 9.

Input Characteristics

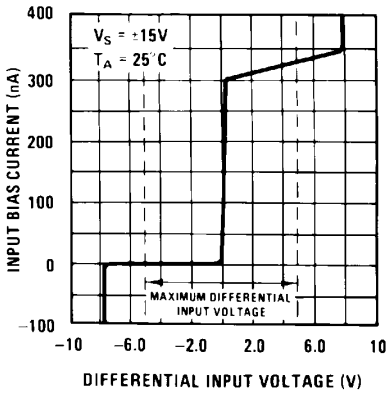


Figure 10.

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Typical Performance Characteristics (continued)

Response Time for Various Input Overdrives

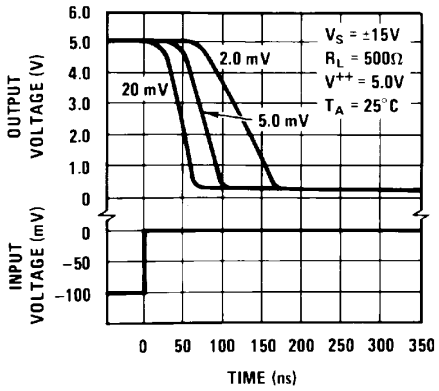


Figure 11.

Response Time for Various Input Overdrives

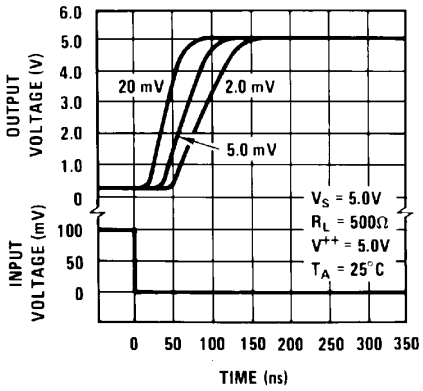


Figure 12.

Output Saturation Voltage

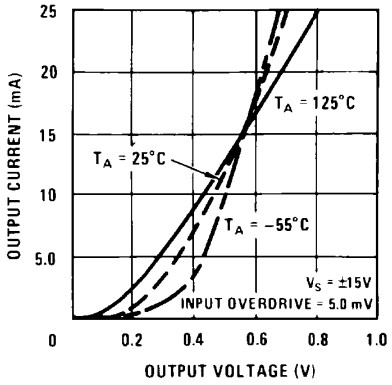


Figure 13.

Supply Current

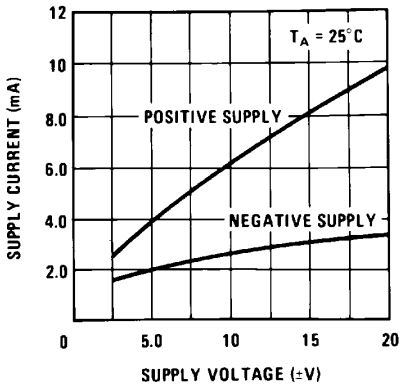


Figure 14.

Supply Current

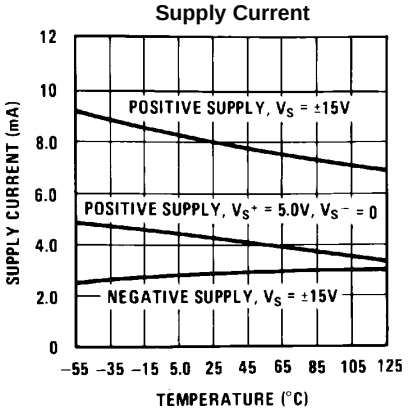


Figure 15.

Output Limiting Characteristics

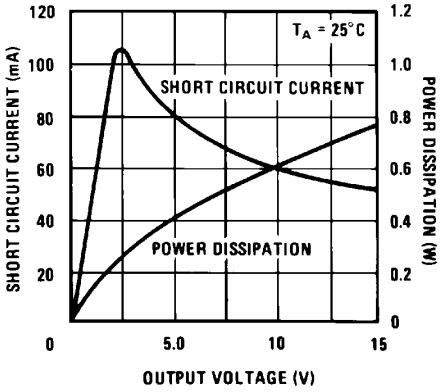
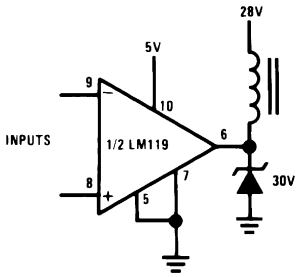


Figure 16.

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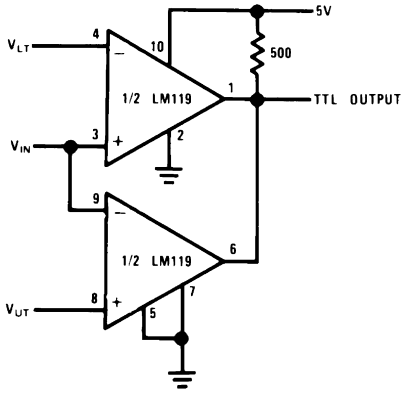
TYPICAL APPLICATIONS

Relay Driver



Pin numbers are for LME0010C package.

Window Detector



V_{OUT} = 5V for $V_{LT} \le V_{IN} \le V_{UT}$
V_{OUT} = 0 for $V_{IN} \le V_{LT}$or $V_{IN} \ge V_{UT}$

REVISION HISTORY

Date Released	Revision	Section	Originator	Changes
07/24/08	A	New release to corporate format	L. Lytle	2 MDS datasheets converted into one corporate data sheet format. Added Radiation information. MDS data sheets MNLM119-X Rev. 0F1 & MDLM119-X Rev 2A2 will be archived.
01/13/09	B	Features, Ordering Info., Electrical Section, Notes 13 and 14	Larry McGee	Added reference to ELDRS and Die NSID's to data sheet. Correction from: 100k rd(Si) to 100 krad(Si) in ordering info. Changed wording in Notes 13 and 14 Revision A will be Archived.
03/26/2013	B	All Sections		Changed layout of National Data Sheet to TI format

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9679801VCA	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119J-QMLV 5962-9679801VCA Q
5962R9679801V9A	Active	Production	DIESALE (Y) | 0	32 | NOT REQUIRED	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	
5962R9679801VCA	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119JRQMLV 5962R9679801VCA Q
5962R9679801VHA	Active	Production	CFP (NAD) | 10	19 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119W RQMLV Q 5962R96798 01VHA ACO 01VHA >T
5962R9679801VIA	Active	Production	TO-100 (LME) | 10	20 | JEDEC TRAY (5+1)	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119HRQMLV 5962R9679801VIA Q ACO 5962R9679801VIA Q >T
5962R9679801VXA	Active	Production	CFP (NAC) | 10	124 | JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119WG RQMLV Q 5962R96798 01VXA ACO 01VXA >T
5962R9679802V9A	Active	Production	DIESALE (Y) | 0	32 | NOT REQUIRED	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	
5962R9679802VCA	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119JRLQMLV 5962R9679802VCA Q
5962R9679802VHA	Active	Production	CFP (NAD) | 10	19 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119W RLQMLV Q 5962R96798 02VHA ACO (LM111W, LM119W) 02VHA >T
5962R9679802VIA	Active	Production	TO-100 (LME) | 10	20 | JEDEC TRAY (5+1)	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119HRLQMLV 5962R9679802VIA Q ACO 5962R9679802VIA Q >T

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962R9679802VXA	Active	Production	CFP (NAC) | 10	124 | JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119WG RLQMLV Q 5962R96798 02VXA ACO 02VXA >T
86014012A	Active	Production	LCCC (NAJ) | 20	50 | TUBE	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119E -SMD Q 5962-86014 012A ACO 012A >T
8601401CA	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119J-SMD 5962-8601401CA Q
8601401HA	Active	Production	CFP (NAD) | 10	19 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119W -SMD Q 5962-86014 01HA ACO 01HA >T
8601401IA	Active	Production	TO-100 (LME) | 10	20 | TRAY NON-STD	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119H-SMD 5962-8601401IA Q A CO 5962-8601401IA Q > T
LM119 MD8	Active	Production	DIESALE (Y) | 0	192 | JEDEC TRAY (5+1)	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	
LM119 MDE	Active	Production	DIESALE (Y) | 0	32 | NOT REQUIRED	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	
LM119 MDR	Active	Production	DIESALE (Y) | 0	32 | NOT REQUIRED	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	
LM119E-SMD	Active	Production	LCCC (NAJ) | 20	50 | TUBE	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119E -SMD Q 5962-86014 012A ACO 012A >T
LM119E/883	Active	Production	LCCC (NAJ) | 20	50 | TUBE	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119E /883 Q ACO /883 Q >T

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM119H-SMD	Active	Production	TO-100 (LME) | 10	20 | TRAY NON-STD	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119H-SMD 5962-8601401IA Q A CO 5962-8601401IA Q > T
LM119H/883	Active	Production	TO-100 (LME) | 10	20 | TRAY NON-STD	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119H/883 Q ACO LM119H/883 Q >T
LM119HRLQMLV	Active	Production	TO-100 (LME) | 10	20 | JEDEC TRAY (5+1)	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119HRLQMLV 5962R9679802VIA Q ACO 5962R9679802VIA Q >T
LM119HRQMLV	Active	Production	TO-100 (LME) | 10	20 | JEDEC TRAY (5+1)	No	Call TI	Level-1-NA-UNLIM	-55 to 125	LM119HRQMLV 5962R9679801VIA Q ACO 5962R9679801VIA Q >T
LM119J-QMLV	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119J-QMLV 5962-9679801VCA Q
LM119J-SMD	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119J-SMD 5962-8601401CA Q
LM119J/883	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119J/883 Q
LM119JRLQMLV	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119JRLQMLV 5962R9679802VCA Q
LM119JRQMLV	Active	Production	CDIP (J) | 14	25 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119JRQMLV 5962R9679801VCA Q
LM119W-SMD	Active	Production	CFP (NAD) | 10	19 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119W -SMD Q 5962-86014 01HA ACO 01HA >T
LM119W/883	Active	Production	CFP (NAD) | 10	19 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119W /883 Q ACO /883 Q >T

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM119WGRLQMLV	Active	Production	CFP (NAC) | 10	124 | JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119WG RLQMLV Q 5962R96798 02VXA ACO 02VXA >T
LM119WGRQMLV	Active	Production	CFP (NAC) | 10	124 | JEDEC TRAY (5+1)	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119WG RQMLV Q 5962R96798 01VXA ACO 01VXA >T
LM119WRLQMLV	Active	Production	CFP (NAD) | 10	19 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119W RLQMLV Q 5962R96798 02VHA ACO (LM111W, LM119W) 02VHA >T
LM119WRQMLV	Active	Production	CFP (NAD) | 10	19 | TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM119W RQMLV Q 5962R96798 01VHA ACO 01VHA >T

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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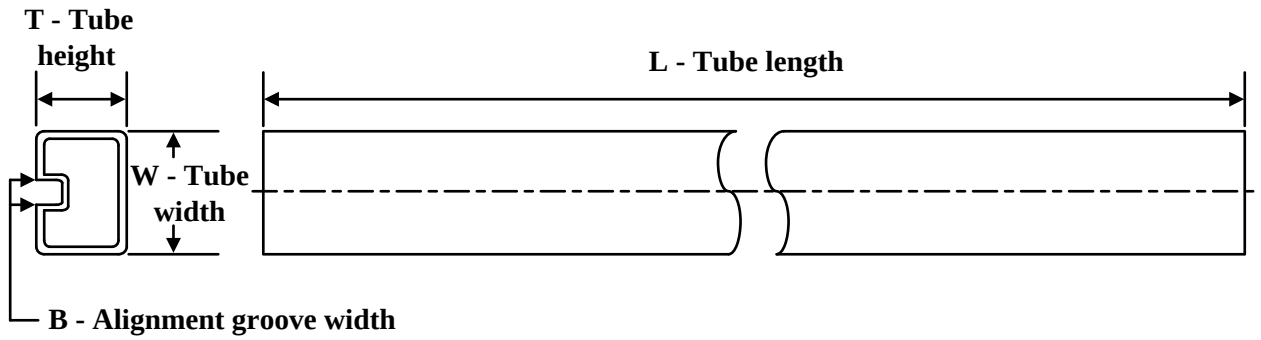
OTHER QUALIFIED VERSIONS OF LM119QML, LM119QML-SP :

- Military : LM119QML
- Space : LM119QML-SP

NOTE: Qualified Version Definitions:

- Military - QML certified for Military and Defense Applications
- Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

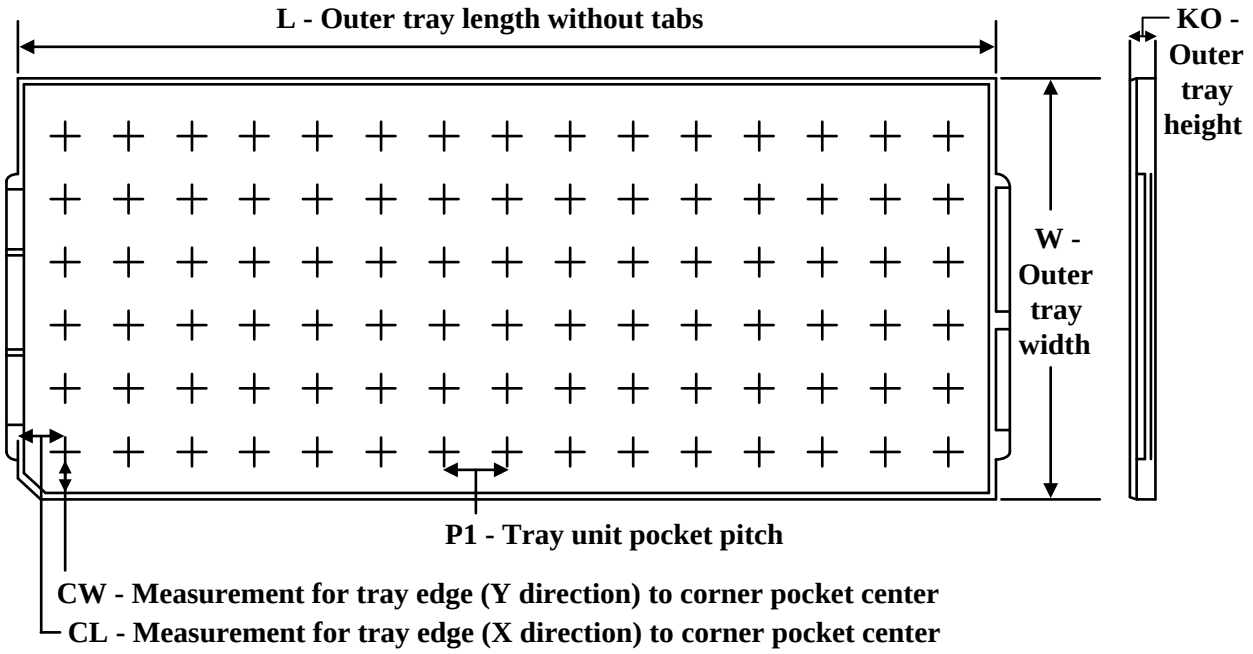
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9679801VCA	J	CDIP	14	25	506.98	15.24	13440	NA
5962R9679801VCA	J	CDIP	14	25	506.98	15.24	13440	NA
5962R9679801VCA	J	CDIP	14	25	506.98	15.24	13440	NA
5962R9679801VHA	NAD	CFP	10	19	502	23	9398	9.78
5962R9679802VCA	J	CDIP	14	25	506.98	15.24	13440	NA
5962R9679802VCA	J	CDIP	14	25	506.98	15.24	13440	NA
5962R9679802VHA	NAD	CFP	10	19	502	23	9398	9.78
86014012A	NAJ	LCCC	20	50	470	11	3810	0
8601401CA	J	CDIP	14	25	506.98	15.24	13440	NA
8601401HA	NAD	CFP	10	19	502	23	9398	9.78
LM119E-SMD	NAJ	LCCC	20	50	470	11	3810	0
LM119E/883	NAJ	LCCC	20	50	470	11	3810	0
LM119J-QMLV	J	CDIP	14	25	506.98	15.24	13440	NA
LM119J-SMD	J	CDIP	14	25	506.98	15.24	13440	NA
LM119J/883	J	CDIP	14	25	506.98	15.24	13440	NA
LM119JRLQMLV	J	CDIP	14	25	506.98	15.24	13440	NA
LM119JRLQMLV	J	CDIP	14	25	506.98	15.24	13440	NA
LM119JRQMLV	J	CDIP	14	25	506.98	15.24	13440	NA
LM119JRQMLV	J	CDIP	14	25	506.98	15.24	13440	NA
LM119W-SMD	NAD	CFP	10	19	502	23	9398	9.78
LM119W/883	NAD	CFP	10	19	502	23	9398	9.78
LM119WRLQMLV	NAD	CFP	10	19	502	23	9398	9.78
LM119WRQMLV	NAD	CFP	10	19	502	23	9398	9.78

TRAY

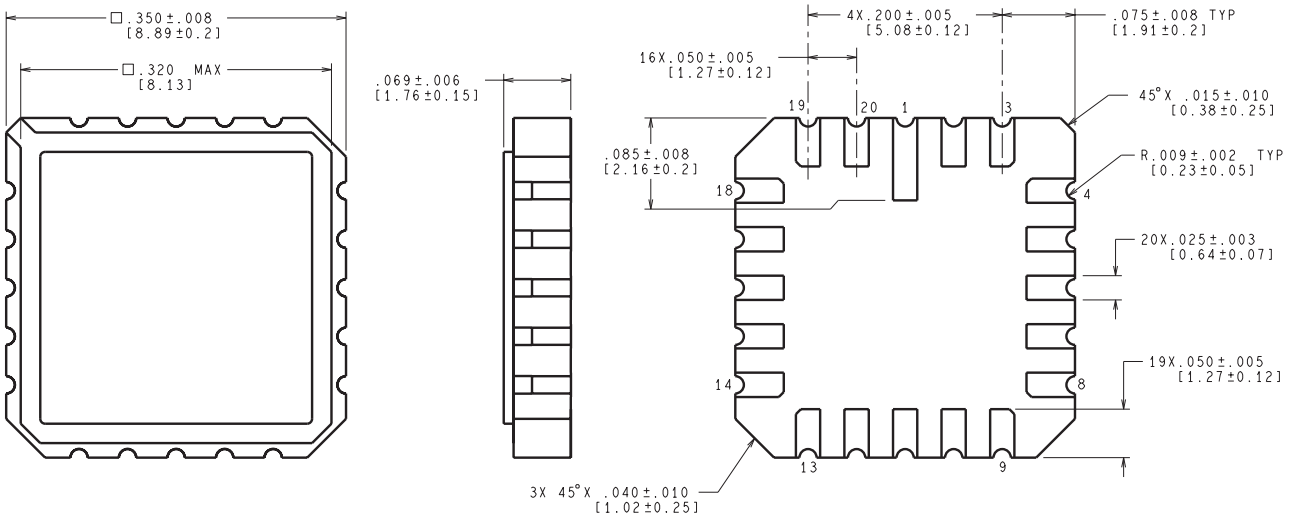


Chamfer on Tray corner indicates Pin 1 orientation of packed units.

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	K0 (µm)	P1 (mm)	CL (mm)	CW (mm)
5962R9679801VIA	LME	TO-CAN	10	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54
5962R9679802VIA	LME	TO-CAN	10	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54
8601401IA	LME	TO-CAN	10	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54
LM119H-SMD	LME	TO-CAN	10	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54
LM119H/883	LME	TO-CAN	10	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54
LM119HRLQMLV	LME	TO-CAN	10	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54
LM119HRQMLV	LME	TO-CAN	10	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54

NAJ0020A



CONTROLLING DIMENSION IS INCH
VALUES IN [ ] ARE MILLIMETERS

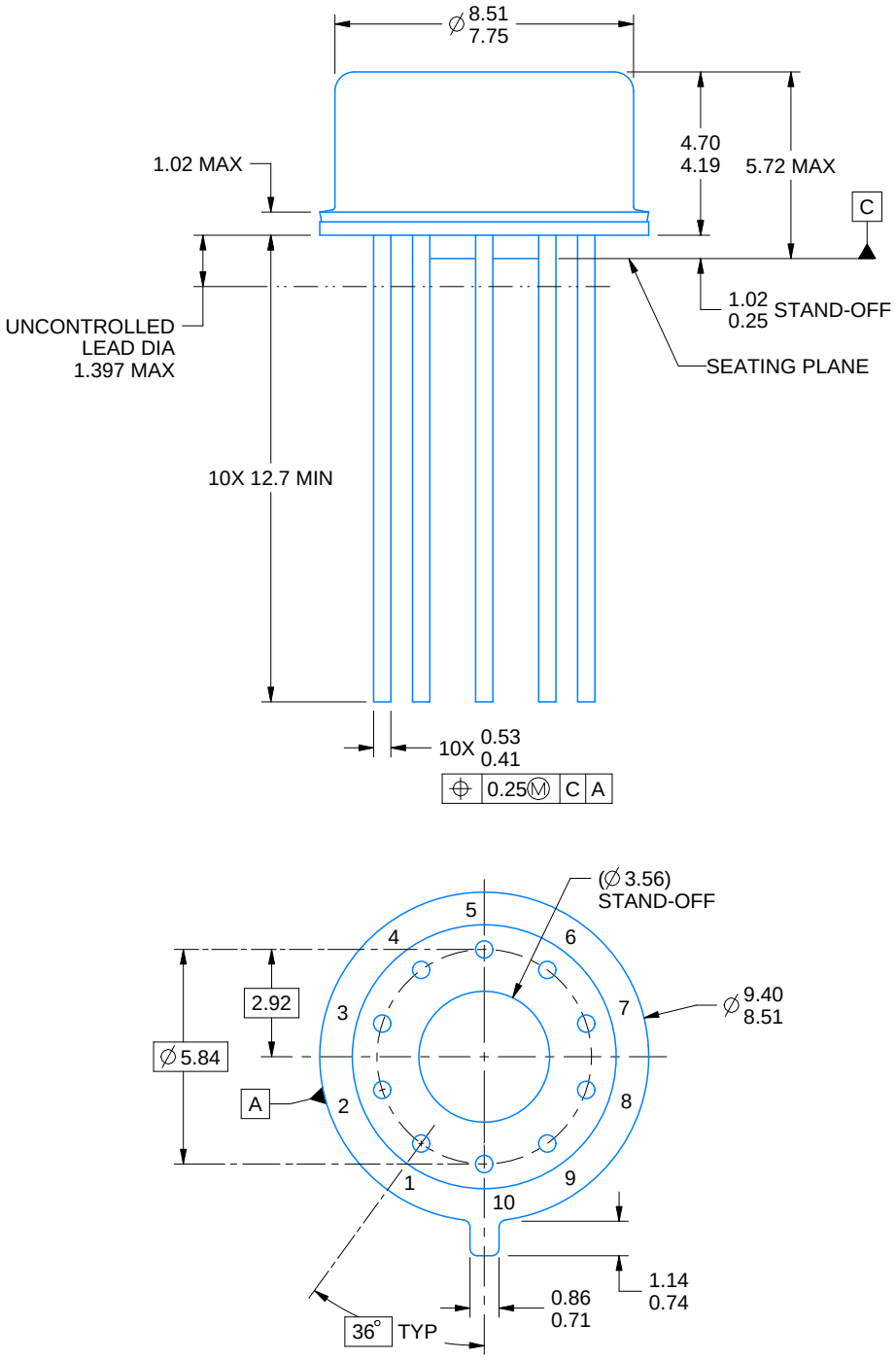
E20A (Rev F)

PACKAGE OUTLINE

LME0010A

TO-CAN - 5.72 mm max height

TRANSISTOR OUTLINE



4220604/B 09/2024

NOTES:

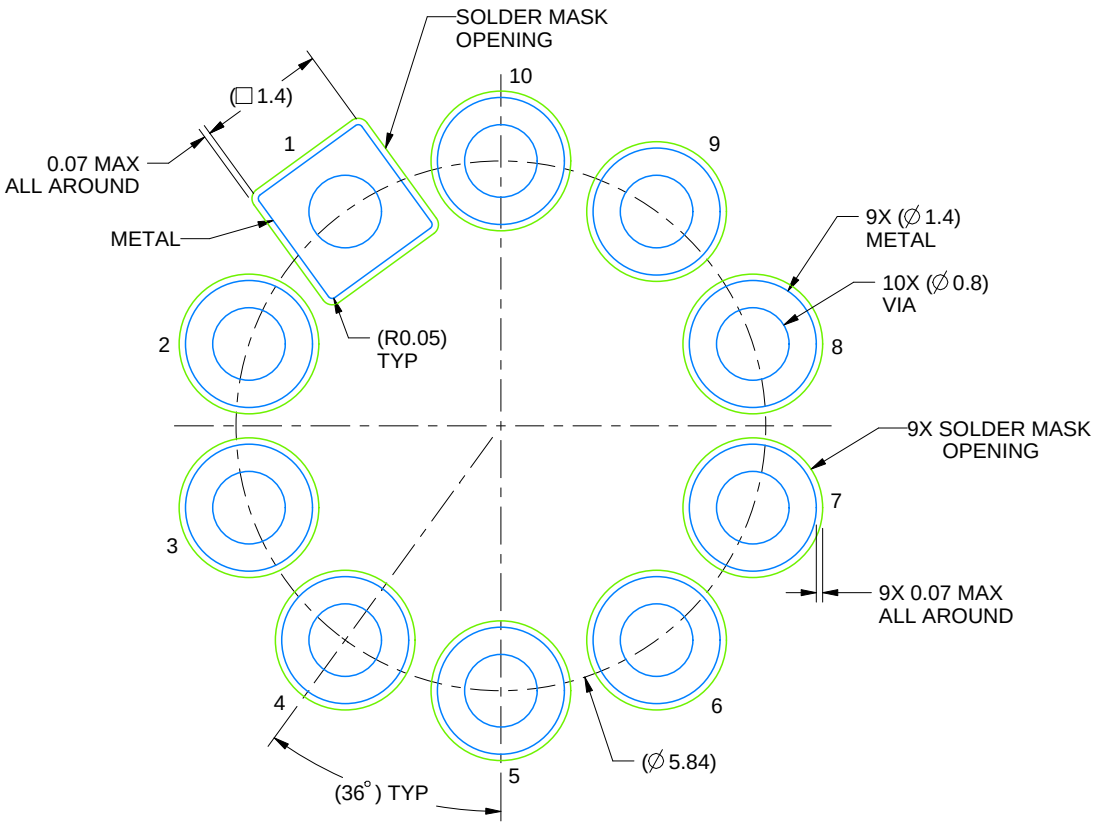
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration MO-006/TO-100.

EXAMPLE BOARD LAYOUT

LME0010A

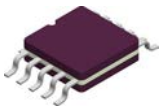
TO-CAN - 5.72 mm max height

TRANSISTOR OUTLINE



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE: 12X

4220604/B 09/2024

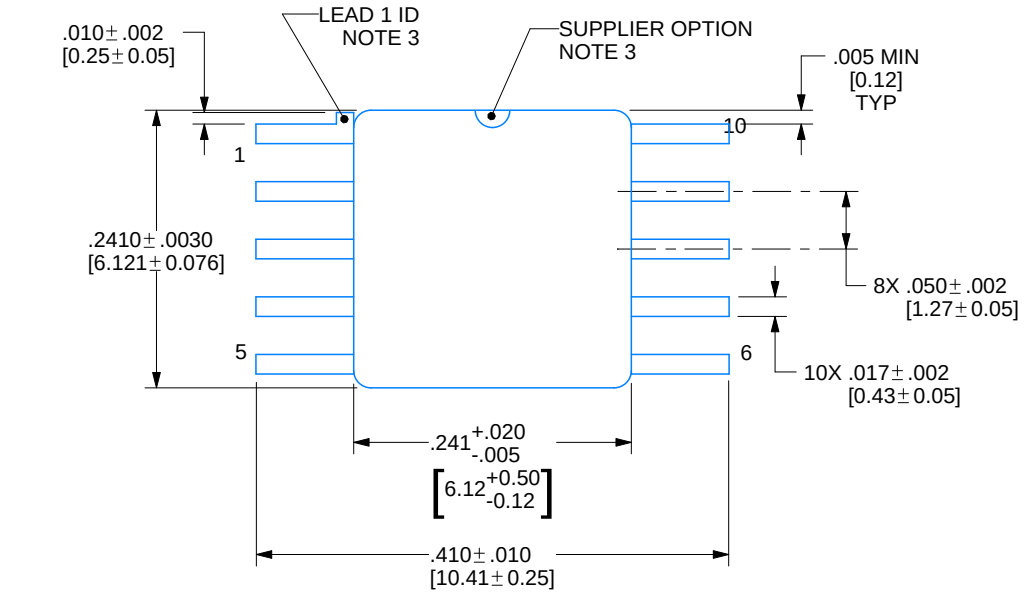


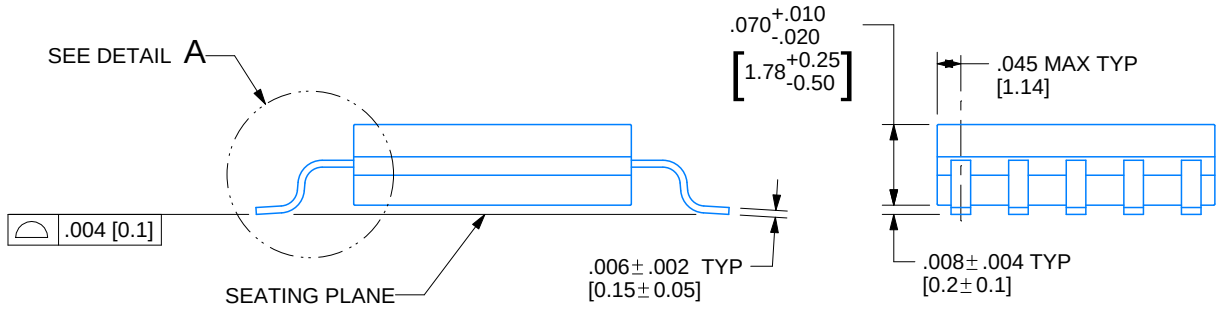
PACKAGE OUTLINE

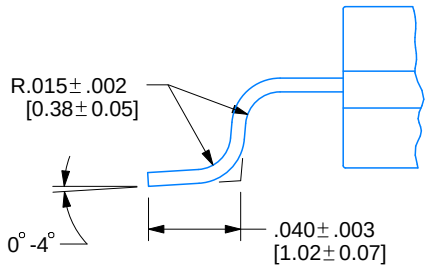
NAC0010A

CFP - 2.33mm max height

CERAMIC FLATPACK







DETAIL A
TYPICAL

4215196/D 08/2022

NOTES:

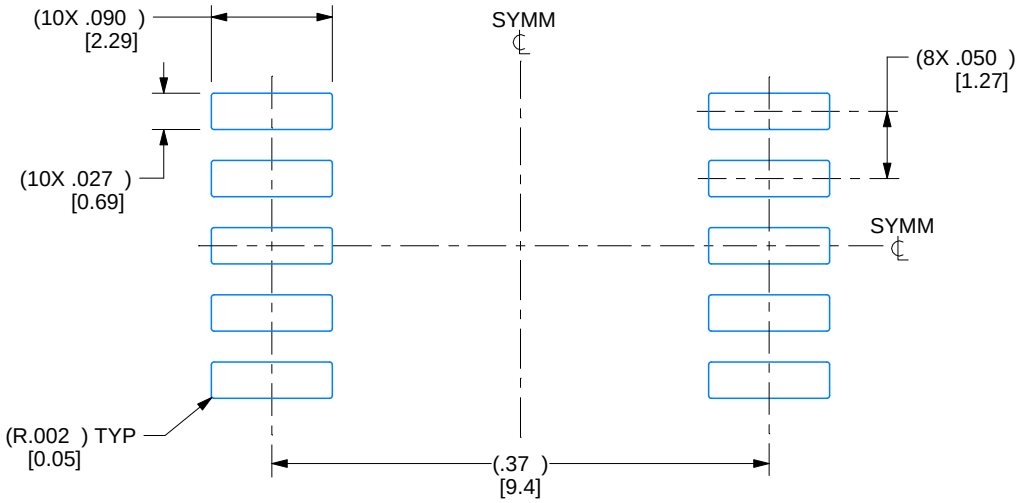
1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. For solder thickness and composition, see the "Lead Finish Composition/Thickness" link in the packaging section of the Texas Instruments website
3. Lead 1 identification shall be:
   a) A notch or other mark within this area
   b) A tab on lead 1, either side
4. No JEDEC registration as of December 2021

EXAMPLE BOARD LAYOUT

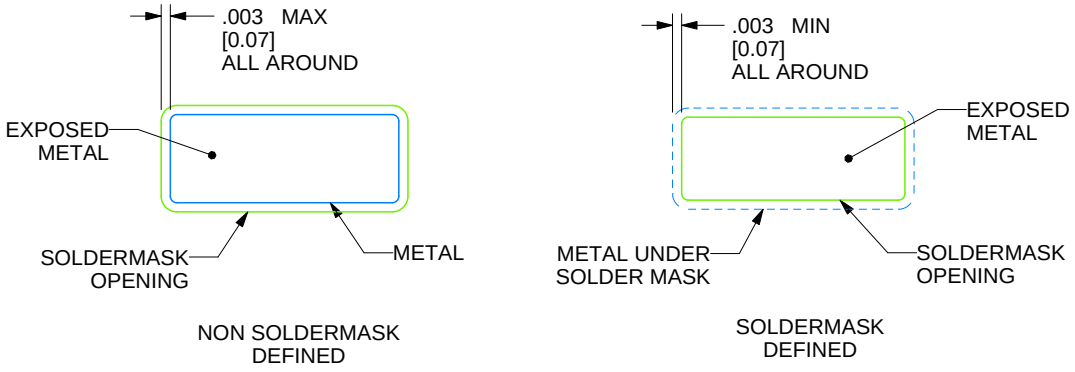
NAC0010A

CFP - 2.33mm max height

CERAMIC FLATPACK



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 7X



4215196/D 08/2022

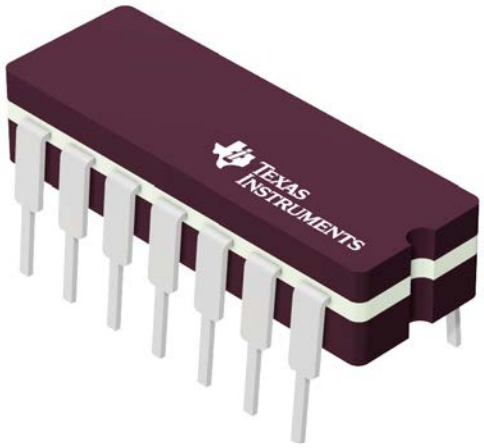
REVISIONS

REV	DESCRIPTION	E.C.N.	DATE	BY/APP'D
A	RELEASE TO DOCUMENT CONTROL	2197877	12/30/2021	DAVID CHIN / ANIS FAUZI
B	NO CHANGE TO DRAWING; REVISION FOR YODA RELEASE;	2198820	02/14/2022	K. SINCERBOX
C	CHANGE PIN 1 ID LOCATION ON PIN	2198845	02/18/2022	D. CHIN / K. SINCERBOX
D	.2410± .0030 WAS .2700 +.0012/-.0002;	2200915	08/08/2022	D. CHIN / K. SINCERBOX

GENERIC PACKAGE VIEW

J 14 CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4040083-5/G

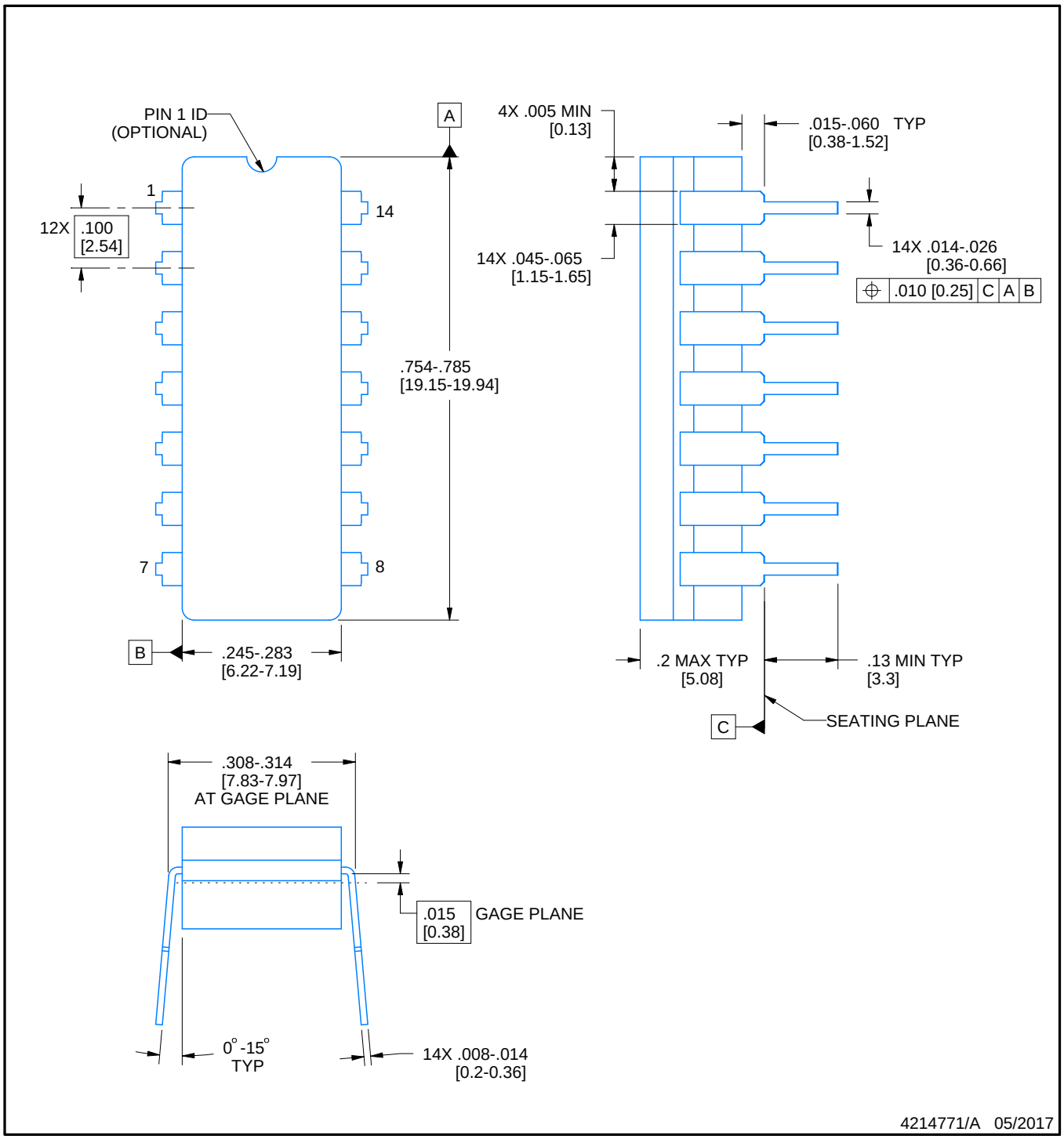


PACKAGE OUTLINE

J0014A

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



NOTES:

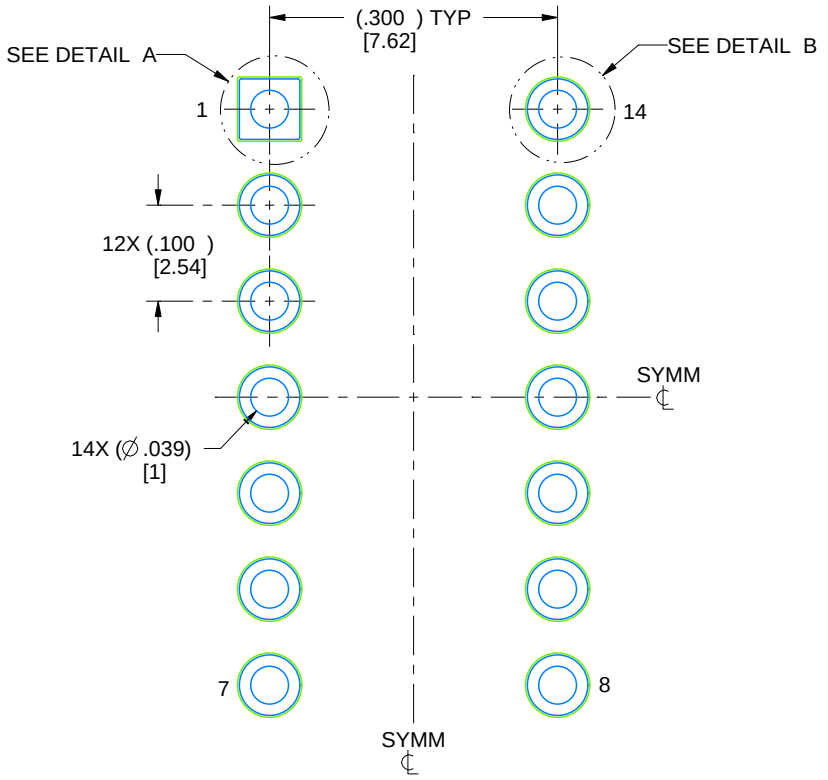
1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package is hermitically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
5. Falls within MIL-STD-1835 and GDIP1-T14.

EXAMPLE BOARD LAYOUT

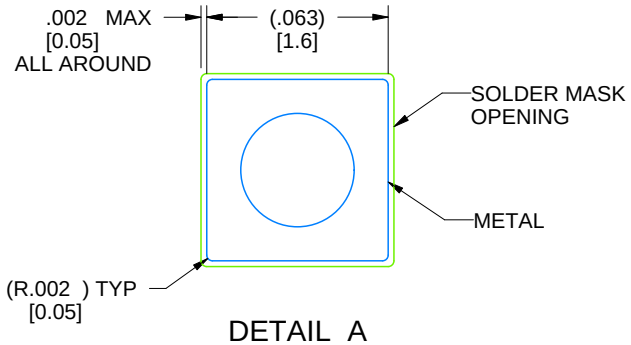
J0014A

CDIP - 5.08 mm max height

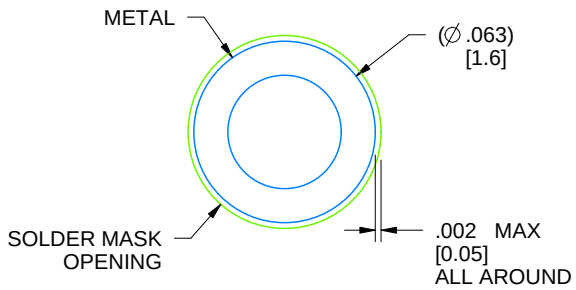
CERAMIC DUAL IN LINE PACKAGE



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE: 5X



DETAIL A
SCALE: 15X



DETAIL B
13X, SCALE: 15X

4214771/A 05/2017

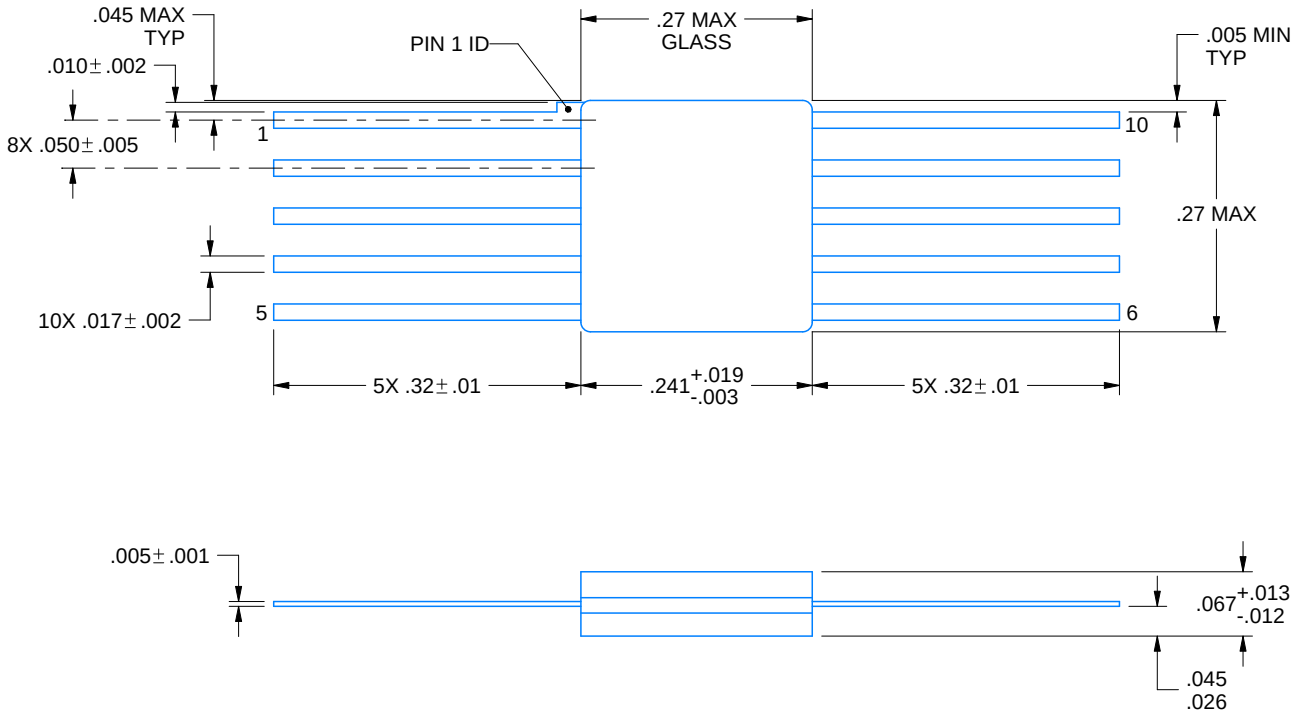
NAD0010A



PACKAGE OUTLINE

CFP - 2.03 mm max height

CERAMIC FLATPACK



4215191/A 06/2021

NOTES:

1. All linear dimensions are in inches. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

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